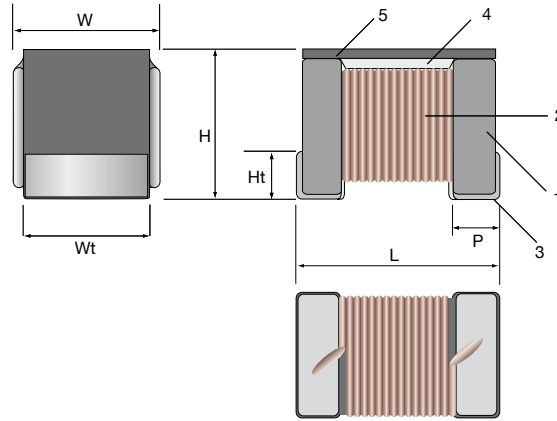


**AIR CORE
WIREWOUND
CHIP INDUCTOR
KQ 1008**



STRUCTURE

- 1 Ceramic core
- 2 Winding wire
- 3 Electrode
- 4 Inner coat
- 5 Flat top film



IDENTIFICATION

PRODUCT CODE	BODY COLOR	MARKING
KQ 1008	Black	3 digit inductance code

Products with Pb-free terminations meet RoHS requirements

TYPE DESIGNATION (HOW TO ORDER)

KQ1008	T	TE	R39	J
PRODUCT CODE	TERMINATION SURFACE MATERIAL	TAPING* TE, BK	NOMINAL INDUCTANCE 3 digits code (see rating table)	INDUCTANCE TOLERANCE
	T: Sn L: Sn/Pb	*Please see "PACKAGING"		

FEATURES

- Small chip inductors of air-core (wirewound type)
- High Q and high self-resonant frequency
- Low DC resistance and high allowable DC current
- Excellent mountability, solderability and high reliability
- Suitable for high-frequency circuits in telecommunication equipment and mobile phones
- Operating temperature range: - 40° C ... +125° C
- Flat top suitable for high speed mounting
- Suitable for reflow soldering
- Lab Kit available

DIMENSIONS (mm)

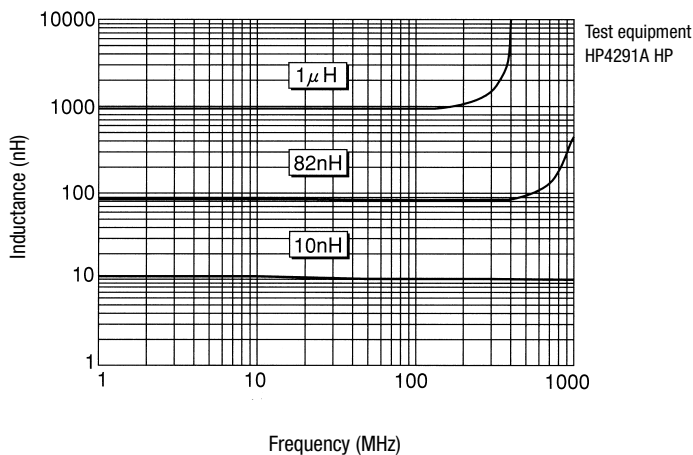
PRODUCT CODE	L	W	H	Wt	Ht	P
KQ1008	2.5 ± 0.2	2.2 ± 0.2	1.8 ^{+0.2} ₋₀	2.0 ± 0.1	0.45 ± 0.15	0.45 ± 0.1

Specifications given herein may be changed at any time without prior notice. Please confirm technical specifications before you order and/or use.

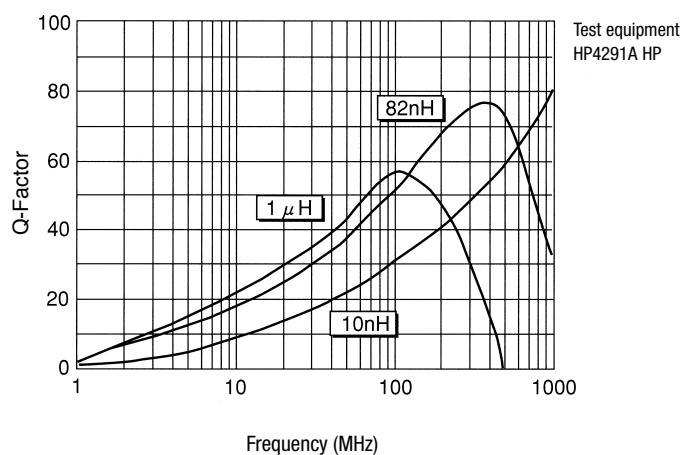
TYPICAL FREQUENCY CHARACTERISTICS

Test equipment: Agilent 4291A impedance analyzer

INDUCTANCE vs. FREQUENCY



Q-FACTOR vs. FREQUENCY



AIR CORE WIREWOUND CHIP INDUCTOR KQ 1008

RATING

TYPE	INDUCTANCE			QUALITY FACTOR		SELF-RESONANT FREQUENCY (MIN.)	DC RESISTANCE (MAX.)	ALLOWABLE DC CURRENT (MAX.)
	NOM. VALUE	FREQUENCY	TOLERANCE	Q (MIN.)	FREQUENCY			
KQ1008□TE 10N □	10 nH	50 MHz	J (± 5%) K (± 10%) M (± 20%)	50	500 MHz	4100 MHz	0.08 Ω	1000 mA
KQ1008□TE 12N □	12 nH					3300 MHz	0.09 Ω	
KQ1008□TE 15N □	15 nH					3000 MHz	0.10 Ω	
KQ1008□TE 18N □	18 nH					2500 MHz	0.11 Ω	
KQ1008□TE 22N □	22 nH					2400 MHz	0.12 Ω	
KQ1008□TE 27N □	27 nH					1600 MHz	0.13 Ω	
KQ1008□TE 33N □	33 nH			350 MHz	60	1500 MHz	0.15 Ω	
KQ1008□TE 39N □	39 nH					1300 MHz	0.16 Ω	
KQ1008□TE 47N □	47 nH					1000 MHz	0.18 Ω	
KQ1008□TE 56N □	56 nH					950 MHz	0.20 Ω	
KQ1008□TE 68N □	68 nH					850 MHz	0.22 Ω	
KQ1008□TE 82N □	82 nH					750 MHz	0.27 Ω	
KQ1008□TE R10 □	0.10 μH	25 MHz	G (± 2%) J (± 5%) K (± 10%)	60	100 MHz	700 MHz	0.56 Ω	650 mA
KQ1008□TE R12 □	0.12 μH					600 MHz	0.63 Ω	650 mA
KQ1008□TE R15 □	0.15 μH					570 MHz	0.70 Ω	580 mA
KQ1008□TE R18 □	0.18 μH					500 MHz	0.77 Ω	620 mA
KQ1008□TE R22 □	0.22 μH					450 MHz	0.84 Ω	500 mA
KQ1008□TE R27 □	0.27 μH					415 MHz	0.91 Ω	500 mA
KQ1008□TE R33 □	0.33 μH			50 MHz	45	375 MHz	1.05 Ω	450 mA
KQ1008□TE R39 □	0.39 μH					375 MHz	1.12 Ω	470 mA
KQ1008□TE R47 □	0.47 μH					360 MHz	1.19 Ω	470 mA
KQ1008□TE R56 □	0.56 μH					350 MHz	1.33 Ω	400 mA
KQ1008□TE R62 □	0.62 μH					320 MHz	1.40 Ω	300 mA
KQ1008□TE R68 □	0.68 μH					290 MHz	1.47 Ω	400 mA
KQ1008□TE R75 □	0.75 μH	7.9 MHz	35	20	25 MHz	375 MHz	1.54 Ω	360 mA
KQ1008□TE R82 □	0.82 μH					360 MHz	1.61 Ω	400 mA
KQ1008□TE R91 □	0.91 μH					350 MHz	1.68 Ω	400 mA
KQ1008□TE 1R0 □	1.0 μH					320 MHz	1.75 Ω	380 mA
KQ1008□TE 1R2 □	1.2 μH					290 MHz	1.75 Ω	370 mA
KQ1008□TE 1R5 □	1.5 μH					250 MHz	1.60 Ω	310 mA
KQ1008□TE 1R8 □	1.8 μH	7.9 MHz	28	22	25 MHz	200 MHz	1.70 Ω	310 mA
KQ1008□TE 2R2 □	2.2 μH					160 MHz	1.90 Ω	270 mA
KQ1008□TE 2R7 □	2.7 μH					160 MHz	2.20 Ω	250 mA
KQ1008□TE 3R3 □	3.3 μH					140 MHz	2.20 Ω	250 mA
KQ1008□TE 3R9 □	3.9 μH					110 MHz	2.70 Ω	230 mA
KQ1008□TE 4R7 □	4.7 μH					100 MHz	2.80 Ω	230 mA
KQ1008□TE 5R6 □	5.6 μH	7.9 MHz	15	20	7.9 MHz	90 MHz	3.10 Ω	210 mA
KQ1008□TE 6R8 □	6.8 μH					80 MHz	2.10 Ω	240 mA
KQ1008□TE 8R2 □	8.2 μH					70 MHz	2.30 Ω	200 mA
KQ1008□TE 100 □	10 μH					65 MHz	2.50 Ω	170 mA
						60 MHz	2.90 Ω	150 mA

Specifications given herein may be changed at any time without prior notice. Please confirm technical specifications before you order and/or use.

□ Enter the code for termination surface material (T, L)
□ Enter the code for inductance tolerance (G, J, K, M)

TE = 2.000 pcs/reel